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CONTENTS

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BRIEF REPORTS

Electronic structure: wide-band, narrow-band, and strongly correlated systems

- Orthogonal polynomial projectors for the projector augmented wave method
of electronic structure calculations 11 827
N. A. W. Holzwarth, G. E. Matthews, A. R. Tackett, and R. B. Dunning
- Real-space renormalization-group study of the Hubbard model: A modified scheme 11 831
Bibhas Bhattacharyya and Shreekantha Sil
- Gaussian-basis LDA and GGA calculations for alkali-metal equations of state 11 834
John E. Jaffe, Zijong Lin, and Anthony C. Hess
- Mott-Peierls transition in the extended Peierls-Hubbard model 11 838
Eric Jeckelmann
- Anderson transitions in three-dimensional disordered systems with randomly varying magnetic flux 11 842
Tohru Kawarabayashi, Bernhard Kramer, and Tomi Ohtsuki
- Temperature-dependent core-level x-ray photoemission spectroscopy of the organic conductors
(MeCl-DCNQI)₂Cu, (MeBr-DCNQI)₂Cu, and (DI-DCNQI)₂Cu 11 846
O. Akaki, A. Chainani, T. Takahashi, Y. Kashimura, and R. Kato
- Hall effect in crystalline Ni-Fe-Cr alloys showing resistivity minima 11 850
S. Chakraborty and A. K. Majumdar
- Violation of Kohler's rule by the magnetoresistance of a quasi-two-dimensional organic metal 11 854
Ross H. McKenzie, J. S. Qualls, S. Y. Han, and J. S. Brooks
- Variable-range-hopping conduction and dielectric relaxation in disordered Sr_{0.97}(Ti_{1-x}Fe_x)O_{3-δ} 11 858
Chen Ang, J. R. Jurado, Zhi Yu, M. T. Colomer, J. R. Frade, and J. L. Baptista
- Ensemble properties in quantum steady-state nonequilibrium theories 11 862
Carsten Heide and Nikolai F. Schwabe

Semiconductors I: bulk

- Acceleration fluctuation scheme for diffusion noise sources within a generalized impedance field method 11 866
P. Shiktorov, E. Starikov, V. Gružinskis, L. Reggiani, T. González, J. Mateos, D. Pardo, and L. Varani
- Angular dependence of impurity scattering in nonparabolic semiconductors 11 870
A. Dutta, P. S. Mallick, and D. Mukhopadhyay
- High-magnetic-field effects on the terahertz mobility of hot electrons in *n*-type InSb 11 872
E. W. S. Caetano, E. A. Mendes, V. N. Freire, J. A. P. da Costa, and X. L. Lei
- Transverse electric-field-induced magnetophonon resonance in *n*-type germanium 11 875
S. C. Lee, Y. B. Kang, G. Y. Hu, J. Y. Ryu, and S. D. Choi

Semiconductors II: surfaces, interfaces, microstructures, and related topics

- Suppression of Ostwald ripening in In_{0.5}Ga_{0.5}As quantum dots on a vicinal (100) substrate 11 879
Byung Don Min, Yong Kim, Eun Kyu Kim, Suk-Ki Min, and Mann Jang Park
- Surface structure of cesium adsorption on the Si(001) 2×1 surface 11 883
H. Hamamatsu, H. W. Yeom, T. Yokoyama, T. Kayama, and T. Ohta
- Excited Wannier-Stark states in the optical absorption of a superlattice in an electric field 11 887
S. Glutsch and F. Bechstedt



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(Continued)